

View Online at <https://aerobasegroup.com/nsn/5961-00-426-4954>

Inclosure Material:

Ceramic and glass and metal

Overall Length:

0.115 inches

Overall Diameter:

0.061 inches

Function For Which Designed:

Phototransistor

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Gold plated leads and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 collector to emitter voltage/static/base open and 7.0 emitter-to-collector offset voltage

Power Rating Per Characteristic:

50.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Case and terminal surfaces gold

Precious Material:

Gold

Terminal Type And Quantity:

1 case and 2 ribbon

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0